# 2SC5273

## Silicon NPN Triple Diffused

# **HITACHI**

ADE-208-897 (Z) 1st. Edition Sep. 2000

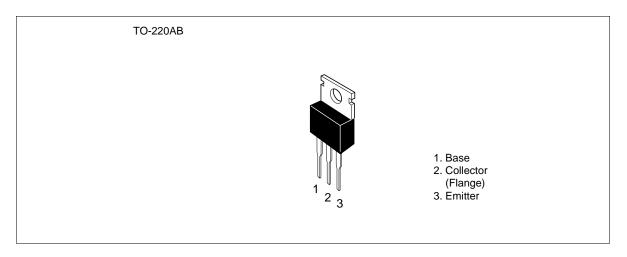
### **Application**

High voltage amplifier

#### **Features**

• High brakedown voltage  $V_{(BR)CEO} = 1300 \text{ V min}$ 

#### Outline





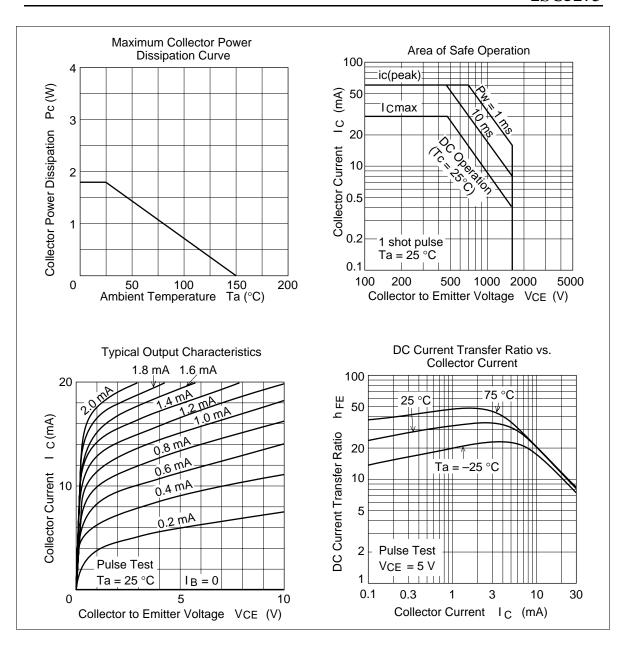
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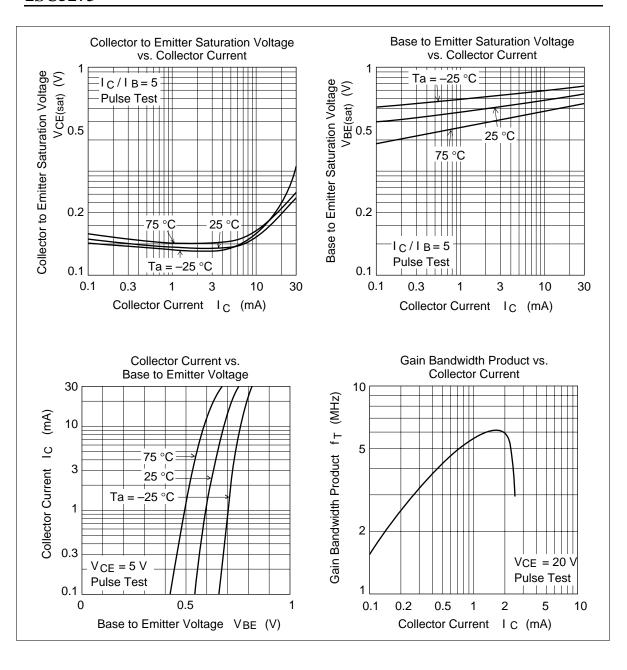
## **Absolute Maximum Ratings** ( $Ta = 25^{\circ}C$ )

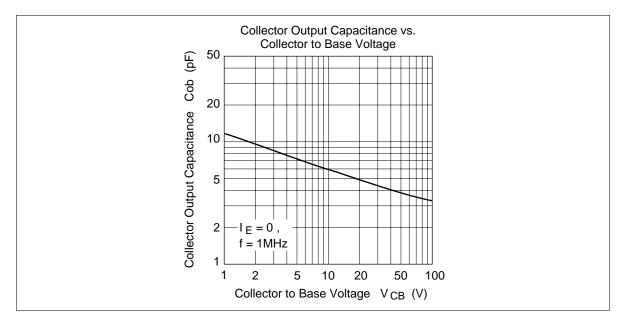
Item	Symbol	Ratings	Unit
Collector to base voltage	V <sub>CBO</sub>	1300	V
Collector to emitter voltage	V <sub>CEO</sub>	1300	V
Emitter to base voltage	$V_{EBO}$	6	V
Collector current	I <sub>c</sub>	30	mA
Collector peak current	I <sub>C(peak)</sub>	60	mA
Collector power dissipation	P <sub>c</sub>	1.8	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

## **Electrical Characteristics** ( $Ta = 25^{\circ}C$ )

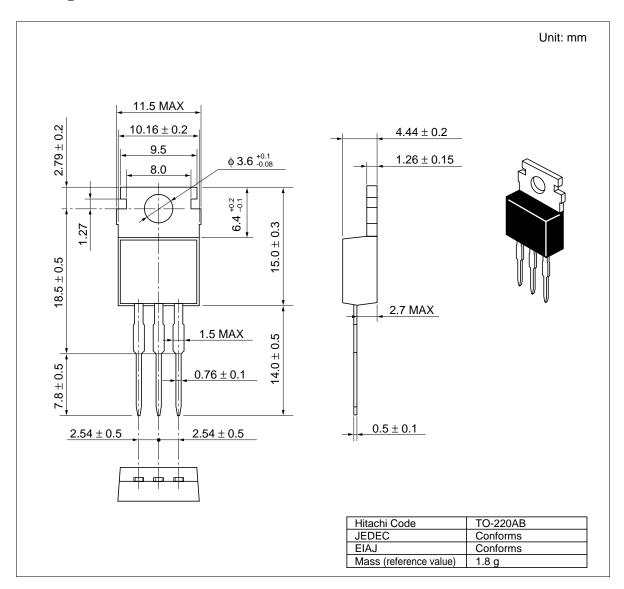
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector cutoff current	I <sub>CES</sub>	_	_	10	μΑ	$V_{CE} = 1300 \text{ V}, R_{BE} = 0$
Collector cutoff current	I <sub>CEO</sub>	_	_	100	μΑ	V <sub>CE</sub> = 1300 V, R <sub>BE</sub> = ∞
Emitter cutoff current	I <sub>EBO</sub>	_	_	10	μΑ	$V_{EB} = 6 \text{ V}, I_{C} = 0$
DC current transfer ratio	h <sub>FE</sub>	10	_	_		$V_{CE} = 5 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	_	5.0	V	$I_{\rm C}$ = 10 mA, $I_{\rm B}$ = 2 mA
Gain bandwidth product	f⊤	_	5.5	_	MHz	$V_{CE} = 20 \text{ V}, I_{C} = 1 \text{ mA}$
Collector output capacitance	Cob	_	3.4	_	pF	$V_{CB} = 100 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$







### **Package Dimensions**



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